

# AR16

**CODE: 16ME1001**

**SET-2**

**ADITYA INSTITUTE OF TECHNOLOGY AND MANAGEMENT, TEKKALI  
(AUTONOMOUS)**

**I B.Tech I Semester Supplementary Examinations, January-2019**

**ENGINEERING DRAWING  
(Common to CE, ME, CSE & IT)**

**Time: 3 Hours**

**Max Marks: 70M**

Answer ONE Question from each Unit

All Questions Carry Equal Marks

All parts of the question must be answered in one place only

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## UNIT-I

1. In a map a 36 km distance is shown by a line 45 cms long. Calculate the R.F. and construct a plain scale to read kilometers and hectometers, for max. 12 km. Show a distance of 8.3 km on it.  
(OR)
2. Draw a straight line AB of any length Mark a point F, 60mm from AB. Trace the path of a point P moving in such a way, that the ratio of its distance from the point F, to its distance from AB is 2:3. Plot at least 10 points. Name each curve. Draw a normal and tangent to each curve at a point on it. 45mm from F.

## UNIT-II

3. Draw the projections of the following points on a common reference line:
  - a. A, 25mm above the HP and 35mm in front of the VP
  - b. B, 25mm above the HP and 40mm behind the VP
  - c. C, 30mm below the HP and 40mm behind the VP
  - d. D, 30mm below the HP and 35mm in front of the VP
  - e. E, 25mm above the HP and in the VP.
  - f. F, 30mm below the HP and in the VP
  - g. G. in both HP& VP.(OR)
4. A line RS 70 mm long has its end R 20 mm above HP and 25 mm in front of VP. The line is inclined to HP and parallel to VP. Draw its projections when the distance between the projectors is 45 mm.

## UNIT-III

5. Draw the projections of a regular hexagon of 25 mm side, having one of its sides in the H.P. and inclined at  $60^\circ$  to the V.P. and its surface making an angle of  $45^\circ$  with the H.P.  
(OR)
6. A semi circular plate of 80 mm diameter has its straight edge in the VP and inclined at  $45^\circ$  to HP. The surface of the plate makes an angle  $30^\circ$  with the VP. Draw its projections

#### UNIT-IV

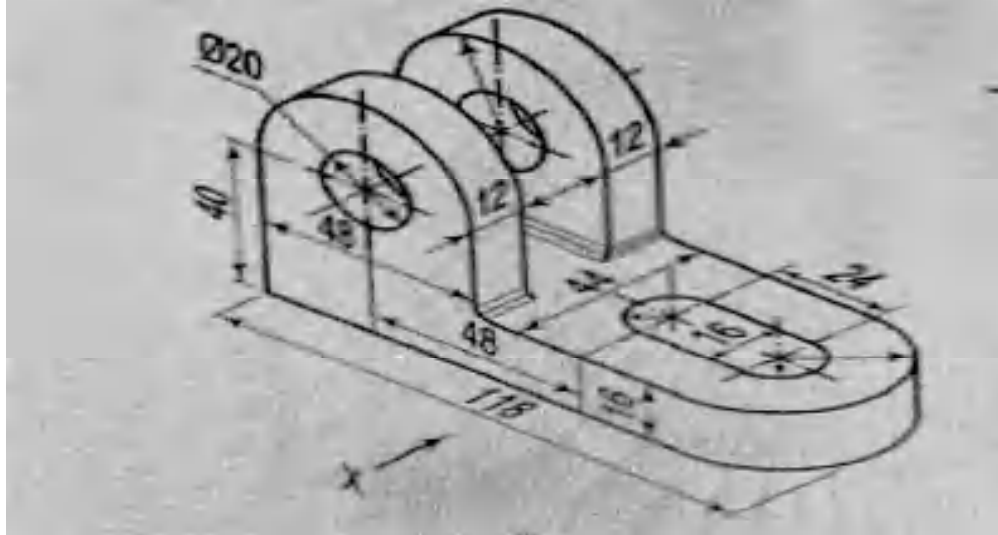
7. A hexagonal prism, side of base 30mm and axis 70mm long rests with one of the edges of its base on HP, such that its axis is inclined at  $30^\circ$  to HP. Draw the projections.

(OR)

8. A cone of base diameter 60mm and altitude 75mm lies on its base on the HP and axis parallel to the VP. Draw its projections.

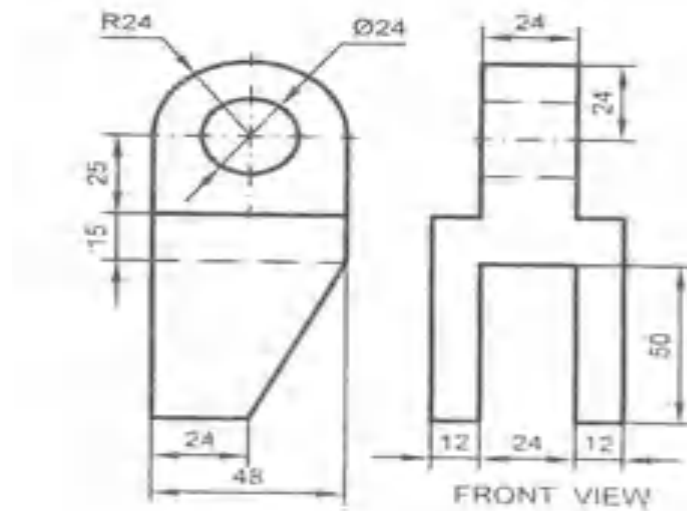
#### UNIT-V

9. Draw the following views of the object shown pictorially in below fig.  
(i) Front view. (ii) Top view. (iii) Side view from the right



(OR)

10. Draw the isometric view of the following orthographic views?



# AR16

**CODE: 16EE1001**

**SET-2**

**ADITYA INSTITUTE OF TECHNOLOGY AND MANAGEMENT, TEKKALI  
(AUTONOMOUS)**

**I B.Tech I Semester Supplementary Examinations, January-2019**

## **BASIC ELECTRIC CIRCUIT ANALYSIS (Electrical and Electronics Engineering)**

**Time: 3 Hours**

**Max Marks: 70M**

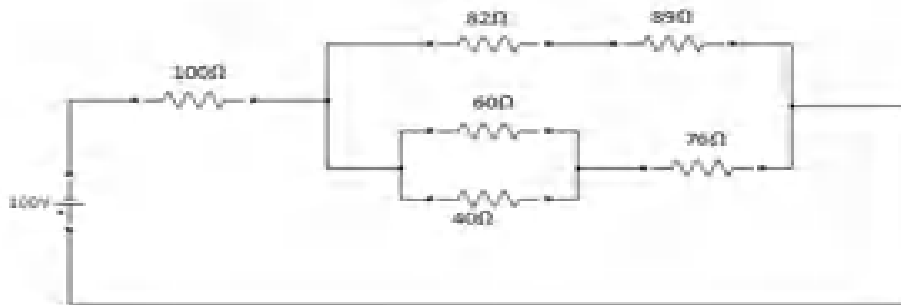
Answer ONE Question from each Unit

All Questions Carry Equal Marks

All parts of the question must be answered in one place only

### **UNIT-I**

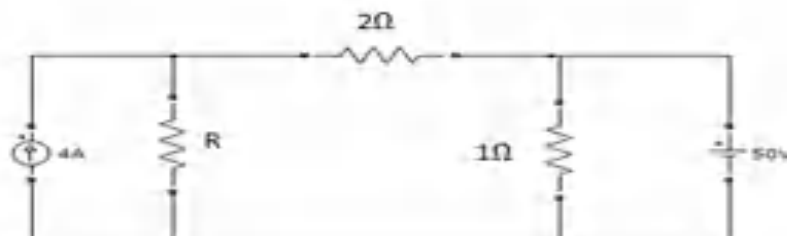
- 1 a) Explain the source transformation with example. [6M]
- b) For the circuit shown in fig 1.find the current through each resistance. [8M]



**Fig.1**

**(OR)**

- 2 a) Explain star to delta transformation with an example [6M]
- b) What is the value of R such that the power supplied by both sources are equal? [8M]



**Fig.2**

## UNIT-II

3. a) Explain the different types induced emf's [6M]  
b) Determine the current in all branches of the circuit shown in fig. 3 using mesh analysis [8M]

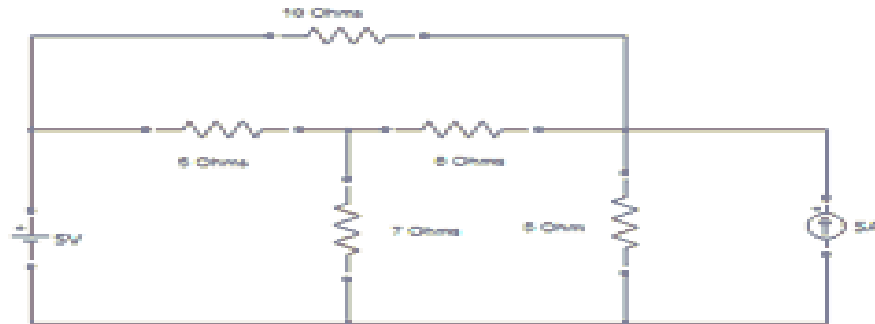


Fig.3  
(OR)

4. a) Obtain the expression for mutual inductance between two coupled coils. [6M]  
b) Obtain the nodal voltage of the circuit shown in fig.4 [8M]

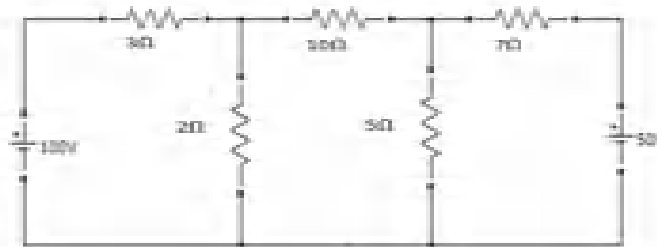


Fig.4

## UNIT-III

5. a) An RLC series circuit has a current which lags the applied voltage by  $45^\circ$ . The voltage across the inductance has a maximum value equal to twice the maximum value of voltage across the capacitor. Voltage across the inductance is  $300\sin(1000t)$  and  $R=20\Omega$ . Find the value of inductance and capacitance? [6M]

- b) Obtain the RMS value of the voltage wave form shown in fig.5

[8M]

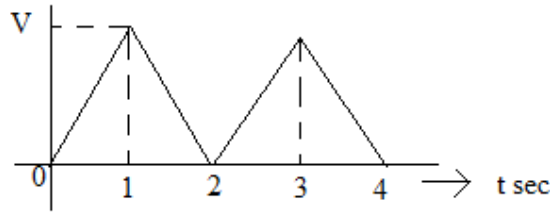


Fig.5

(OR)

6. a) Explain the significance of 'j' operator. What are the different forms of expressing the sinusoidal quantity in complex form? [6M]
- b) The voltage of a circuit is  $v=200\sin(\omega t+30^\circ)$  and the current is  $i=50\sin(\omega t+60^\circ)$  Calculate [8M]
- i) The average power, reactive volt amperes and apparent power
  - ii) Find the circuit elements, if  $\omega=100\pi$  rad/sec.

UNIT-IV

7. An RLC series circuit with a resistance of  $10\Omega$  inductance of  $0.2$  H and a capacitance of  $40\mu\text{F}$  is supplied with a  $100\text{V}$  supply at variable frequency. Find the following w.r.t the series resonant circuit. (a) frequency at which resonance takes place (b) current (c) power (d) power factor (e) voltage across RLC at that time (f) quality factor (g) half power points (h) resonance and phasor diagrams? [14M]

(OR)

8. a) Obtain the expression for the frequency at which maximum voltage occurs across the capacitance in a series resonance circuit in terms of the Q factor and resonant frequency [7M]

- b) For a series RL circuit having variable resistance and fixed inductance, plot the current locus and determine the maximum power consumed. Assume  $X_L=25\Omega$  and  $R=50\Omega$ , the voltage is 200V, 50Hz. [7M]

UNIT-V

9. a) Explain how the reactive power is measured in a 3-phase balanced system [7M]
- b) A balanced delta connected load takes a line current of 15 A when connected to a balanced three phase 400 V system. A wattmeter with its current coil in one line and its potential coil between the two remaining lines read 2000 W. Determine the load impedance [7M]

(OR)

10. Explain the relation between line, phase voltages and currents in a balanced three phase star connected system. [14M]

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# AR16

**CODE: 16EE1002**

**SET-1**

**ADITYA INSTITUTE OF TECHNOLOGY AND MANAGEMENT, TEKKALI  
(AUTONOMOUS)**

**I B.Tech I Semester Supplementary Examinations, January-2019**

## **NETWORK ANALYSIS**

**(Electronics & Communication Engineering)**

**Time: 3 Hours**

**Max Marks: 70**

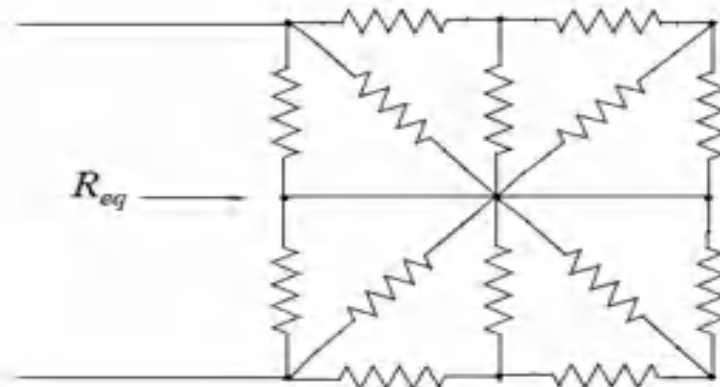
Answer ONE Question from each Unit

All Questions Carry Equal Marks

All parts of the Question must be answered at one place

### **UNIT-I**

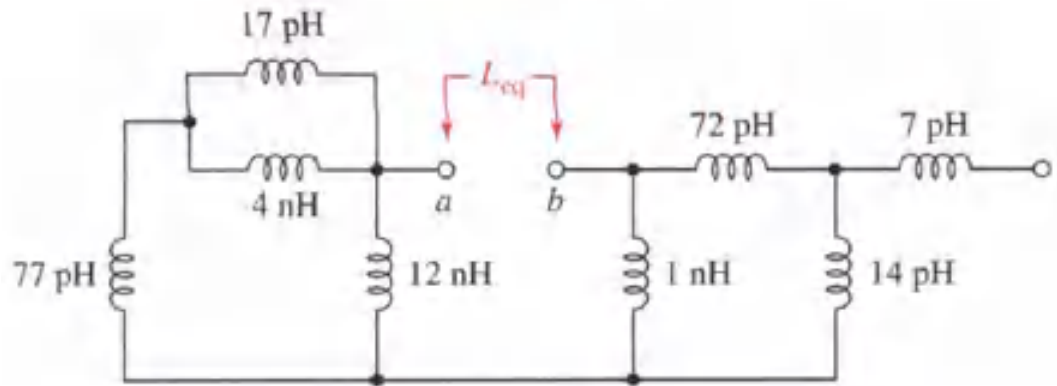
- 1 a) When a DC voltage is applied to a capacitor, the voltage across its terminals is found to build up in accordance with  $V_c = 50(1 - e^{-100t})$ . After a lapse of 0.01 sec the current flow is equal to 2mA. (a) Find the value of capacitance (b) How much energy is stored in electric field at this time? 6M
- b) In the network shown, each resistor is  $10\ \Omega$ . Compute the equivalent resistance. 8M



**(OR)**

2. a) Find equivalent inductance between terminals a & b

8M



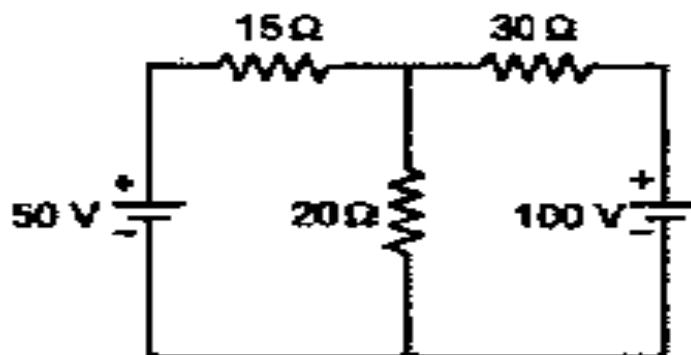
- b) Discuss about Source transformation with suitable example.

6M

## UNIT-II

3. a) Apply Kirchhoff's law's to the given circuit

6M



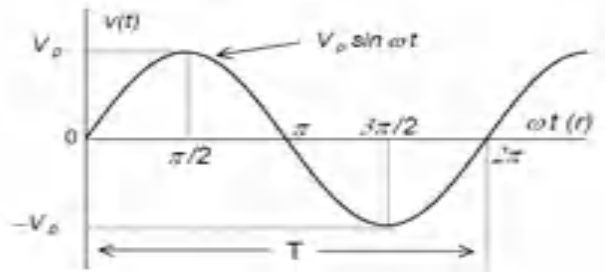
- b) Use nodal analysis, find the voltage at each node of given circuit below.

8M

(OR)



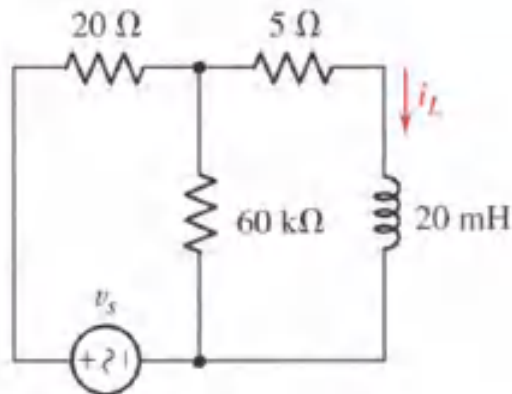
4. a) Compute the average value of the sinusoidal waveform shown in Figure, where denotes the peak (maximum) value of the sinusoidal voltage. 6M



- b) Explain about Star-Delta transformation with example. 8M

### UNIT-III

5. a) Define impedance, admittance, reactance and conductance. 6M  
 b) Let  $V_s = 20 \cos 500t$  v in the circuit. After simplifying the circuit a little, find  $i_L(t)$ . 8M



(OR)

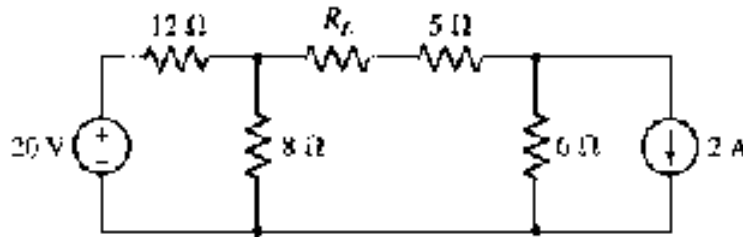
6. Obtain the resonant frequency and quality factor and bandwidth for a series RLC circuit. 14M

### UNIT-IV

7. a) State and explain Norton's theorem with suitable example? 6M  
 b) Apply Superposition theorem for the given circuit below. 8M

(OR)

8. a) If any value whatsoever may be selected for  $R_L$  in the circuit of figure, what is the maximum power that could be dissipated in  $R_L$ ? 8M



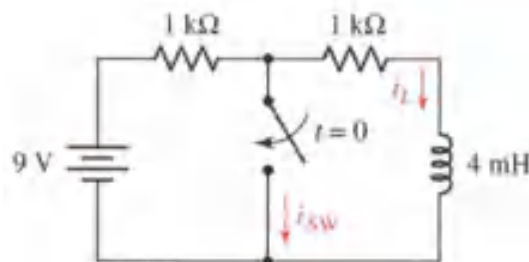
- b) Explain Reciprocity theorem with suitable example 6M

### UNIT-V

9. a) Obtain h parameters in terms of Y parameters 7M  
b) Find [ z ] parameters for the two port shown in figure 7M

(OR)

10. a) After being in the configuration shown for hours, the switch in the circuit of figure is closed at  $t=0$ . At  $t=5\mu\text{sec}$ , calculate: (i)  $i_L$  (ii)  $i_{sw}$ . 8M



- b) Explain in brief the response of RLC parallel circuit 6M

# AR13

CODE: 13ME1001

SET-1

ADITYA INSTITUTE OF TECHNOLOGY AND MANAGEMENT, TEKKALI  
(AUTONOMOUS)

I B.Tech I Semester Supplementary Examinations, January-2019

ENGINEERING DRAWING

(Common to Civil, ME, CSE & IT)

Time: 3 Hours

Max Marks: 70

## PART-A

ANSWER ALL QUESTIONS

[1 x 10 = 10 M]

1. a) Define the term RF used in scales?  
b) What are the types of set squares used in Engineering Drawing?  
c) Define orthographic projection?  
d) Write the position of point in first angle projection?  
e) List the types of planes used in orthographic projection?  
f) If the plane is inclined to HP and corner rests on HP, then what is the position of plane assumed in simple position?  
g) List the solids of revolution?  
h) Define a polyhedron?  
i) Write the advantage of Isometric drawing?  
j) What is the position of top view in first angle projection?

## PART-B

Answer one question from each unit

[5x12=60M]

### UNIT-I

2. Construct a diagonal scale of R.F=1/4000 to show meters and long enough to measure up to 500 meters. 12M

(OR)

3. To construct an ellipse when the distance of the focus from the directrix is equal to 50 mm and eccentricity is  $\frac{2}{3}$ . Also Draw tangent and normal at any point on the curve. 12M

### UNIT-II

4. a) Draw the projections of a point 'A' lying on V.P and 70 mm above HP. 4 M  
b) A line AB 50 mm long is perpendicular to V.P and parallel to HP. Its end A is 20 mm in front of V.P and the line is 40 mm above HP. Draw the projections of the line. 8M

(OR)

5. A line PQ 100 mm long is inclined at  $30^\circ$  to the H.P. and parallel to the V.P. Draw its projections. 12M

### UNIT-III

6. a) A square ABCD of 40 mm side has a corner on the H.P. and 20 mm in front of the V.P. All the sides of the square are equally inclined to the H.P. and parallel to the V.P. Draw its projections? 4M  
b) Draw the projections of a circle of 50 mm diameter having its plane vertical and inclined at  $30^\circ$  to the V.P. Its centre is 30 mm above the H.P. and 20 mm in front of the V.P. 8M

(OR)

7. Draw the projections of a regular hexagon of 25 mm side, having one of its sides in the H.P. and inclined at  $60^\circ$  to the V.P. and its surface making an angle of  $45^\circ$  with the H.P. 12M

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SET-1

## UNIT-IV

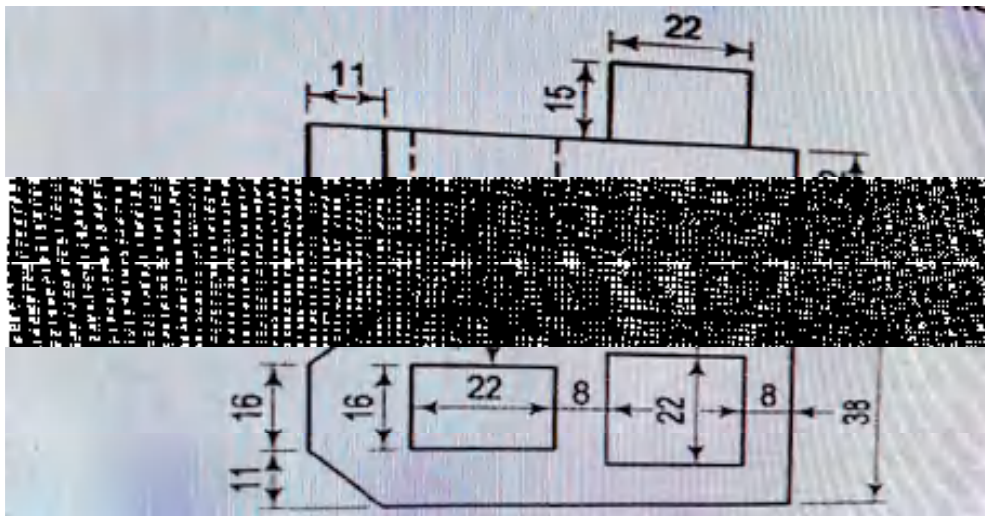
8. a) A cube of 50 mm long edge is resting on the H.P. with its vertical faces equally inclined to the V.P. Draw its projections. 4M
- b) Draw the projections of a pentagonal prism, base 25 mm side and axis 50 mm long, resting on one of its rectangular faces on the H.P. with the axis inclined at  $45^\circ$  to the V.P. 8M

(OR)

9. Draw the projections of a cone, base 45 mm diameter and axis 50 mm long, when it is resting on the ground on its base circle. 12M

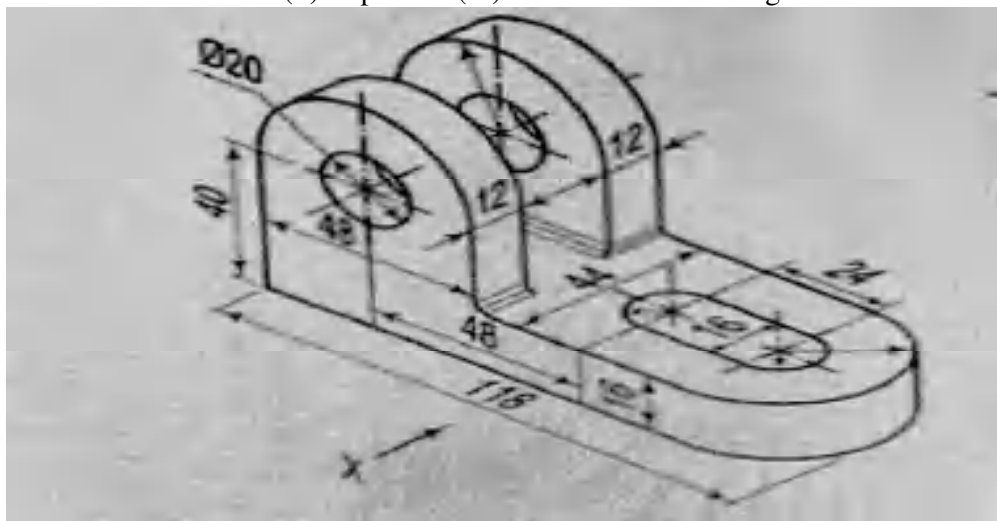
## UNIT-V

10. Draw the isometric view of the casting shown in two views in below fig. 12M



(OR)

11. Draw the following views of the object shown pictorially in below fig. (i). Front view. (ii) Top view. (iii) Side view from the right 12M



# AR13

CODE: 13EC1001

SET-2

ADITYA INSTITUTE OF TECHNOLOGY AND MANAGEMENT, TEKKALI  
(AUTONOMOUS)

I B.Tech I Semester Supplementary Examinations, January-2019

## ELECTRONIC DEVICES

(Electronics and Communication Engineering)

Time: 3 Hours

Max Marks: 70

### PART-A

ANSWER ALL QUESTIONS

[1 x 10 = 10 M]

1. a) Write the relation between E and V  
b) The force on a charged particle in a magnetic field depends on  
c) What is meant by doping  
d) Define fermi level  
e) Define Avalanche break down  
f) Draw the circuit of a Full Wave Rectifier  
g) Compare the widths and doping of collector, base and emitter.  
h) Define Reach Through  
i) Write any two differences between BJT and UJT  
j) List any two applications of Dual Gate MOSFET

### PART-B

Answer one question from each unit

[5x12=60M]

### UNIT-I

2. a) Explain the operation of CRT 6M  
b) In a parallel plate diode, the cathode and anode are spaced 5mm apart and the anode is kept at 220V d.c with respect to cathode. The initial velocity of an electron is  $2 \times 10^6$  m/s in the direction towards anode. Calculate the velocity and time of an electron at midway between cathode and anode. 6M
- (OR)
3. a) Derive the expression for magnetic deflection and sensitivity 6M  
b) Derive the expression for motion of charge in constant electric field 6M

## UNIT-II

4. a) If a donor impurity is added to the extent of one atom per  $10^8$  germanium atoms, calculate its resistivity at  $300^\circ\text{K}$ . If its resistivity without addition of impurity at  $300^\circ\text{K}$  is  $44.64\Omega\text{-cm}$ . comparing two values, comment on the result.  $\mu_n=3800\text{cm}^2/\text{V-sec}$  6M
- b) Explain Hall effect and list any two applications of it. 6M
- (OR)**
5. a) Summarize the formation of P-Type semiconductor. 6M
- b) Explain the importance of continuity equation. 6M

## UNIT-III

6. a) Explain the characteristics of PN junction diode. 10M
- b) List any two applications of Varactor diode 2M
- (OR)**
7. a) Explain the formation of diffusion capacitance and write the expression for it. 6M
- b) Explain how Zener diode can be used as a regulator in reverse bias region. 6M

## UNIT-IV

8. a) Draw the characteristics of transistor in Common Emitter configuration and explain them. 6M
- b) Explain the different current components present in the transistor and describe them 6M
- (OR)**
9. a) Write the analytical expression for collector current  $I_C$  and  $I_E$  and show that  $I_E=I_C+I_B$  6M
- b) Explain the constructional details and operation of a transistor 6M

## UNIT-V

10. a) Explain the operation of Depletion MOSFET with the help of its characteristics. 6M
- b) List any five advantages and one disadvantage of FET over BJT 6M
- (OR)**
11. a) Explain the operation of V-groove MOSFET. 6M
- b) Explain the operation of SCR with the help of its characteristics 6M